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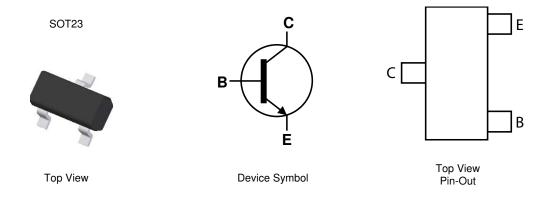
30V NPN MEDIUM POWER TRANSISTOR IN SOT23

Features

- BV_{CEO} > 30V
- I_C = 1A high Continuous Collector Current
- I_{CM} Up to 4A Peak Pulse Current
- Excellent h_{FE} Characteristics Up To 4A
- R_{SAT} = 175mΩ @ 1A for a Low Equivalent On-Resistance
- Low Saturation Voltage < 300mV @ 1A
- 500mW Power Dissipation
- Complementary PNP Type: FMMT589
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT-23
- Case material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <a>©3
- Weight: 0.008 grams (Approximate)



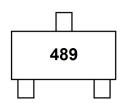
Ordering Information (Note 4)

Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FMMT489TA	489	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



489 = Product Type Marking Code





Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	30	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	1	A
Peak Pulse Current	I _{CM}	4	A
Base Current	I _B	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	500	mW
Thermal Resistance, Junction to Ambient (Note 5)	R _{eJA}	250	°C/W
Thermal Resistance, Junction to Lead (Note 6)	R _{eJL}	197	°C/W
Operating and Storage Temperature Range	T_{J}, T_{STG}	-55 to +150	°C

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes:

^{5.} For a device mounted with the collector lead on 15mm X 15mm 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air

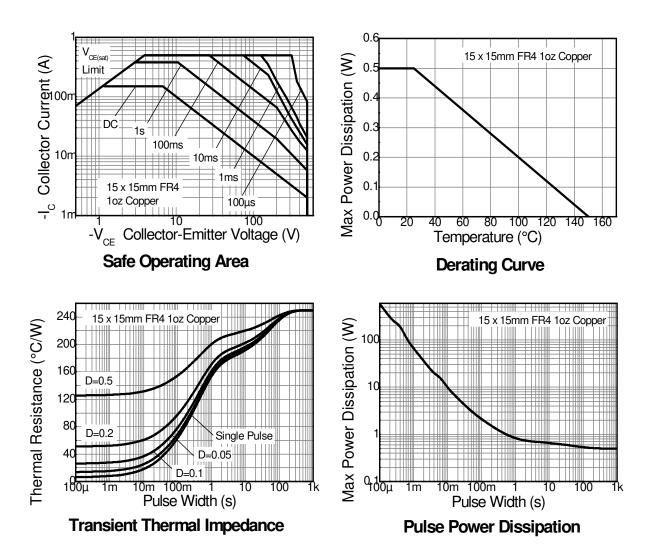
conditions whilst operating in a steady-state.

6. Thermal resistance from junction to solder-point (at the end of the collector lead).

7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information







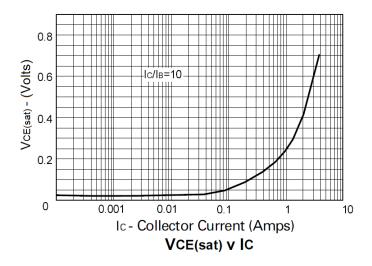
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

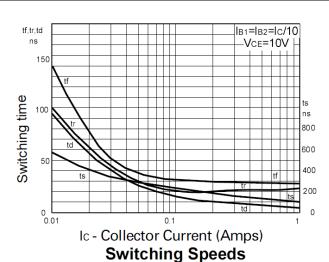
Characteristic	Symbol	Min	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	50		V	I _C = 100 μA
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	30		V	I _C = 10 mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7		V	I _E = 100 μA
Collector-Base Cutoff Current	I _{CBO}		100	nA	V _{CB} = 30V
Emitter-Base Cutoff Current	I _{EBO}		100	nA	V _{EB} = 6V
Collector-Emitter Cutoff Current	I _{CES}		100	nA	V _{CES} = 30V
Static Forward Current Transfer Ratio (Note 8)	h _{FE}	100 100 60 20	- 300 - -		$\begin{split} &I_{C} = 1 \text{mA}, V_{CE} = 2 V \\ &I_{C} = 1 \text{A}, V_{CE} = 2 V \\ &I_{C} = 2 \text{A}, V_{CE} = 2 V \\ &I_{C} = 4 \text{A}, V_{CE} = 2 V \end{split}$
Collector-Emitter Saturation Voltage (Note 8)	V _{CE(sat)}		300 600	mV mV	I _C = 1A, I _B = 100mA I _C = 2A, I _B = 200mA
Base-Emitter Turn-On Voltage (Note 8)	V _{BE(on)}		1.0	V	I _C = 1A, V _{CE} = 2V
Base-Emitter Saturation Voltage (Note 8)	V _{BE(sat)}		1.1	V	I _C = 1A, I _B = 100mA
Output Capacitance	C _{obo}		10	pF	V _{CB} = 10V, f = 1MHz
Transition Frequency	f _T	150		MHz	$V_{CE} = 10V$, $I_C = 50$ mA, $f = 100$ MHz

Note: 8. Measured under pulsed conditions. Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2\%$

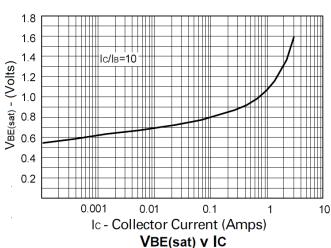


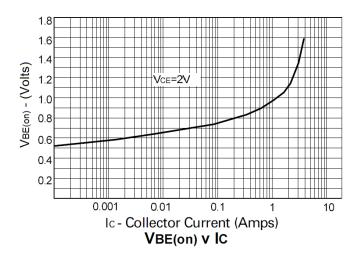
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





200 160 VCE=2V 80 40 0 0.001 0.01 0.1 1 10 Ic - Collector Current (Amps) hFE v IC



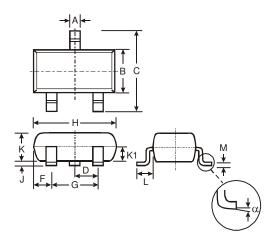






Package Outline Dimensions

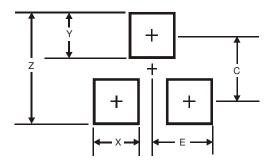
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT23					
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.903	1.10	1.00			
K1	-	-	0.400			
L	0.45	0.61	0.55			
M	0.085	0.18	0.11			
α	0°	8°	-			
All	All Dimensions in mm					

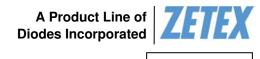
Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	2.9		
Х	0.8		
Υ	0.9		
С	2.0		
Е	1.35		





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